

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	924	349/153 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	OR	OFF	2003/04/25 10:07
		345/206 and (conduct\$ or dummy)and insulat\$ and overlap\$ and (top adj gate)	USPAT	OR	OFF	2001/07/25 09:00
		349/151 and (conduct\$ or dummy)and insulat\$ and overlap\$ and (top adj gate)	USPAT	OR	OFF	2001/07/25 08:59
		349/149 and (conduct\$ or dummy)and insulat\$ and overlap\$ and (top adj gate)	USPAT	OR	OFF	2001/07/25 08:58
		349/149 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	OR	OFF	2001/07/25 08:57
		349/155 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	OR	OFF	2001/07/25 08:56
		349/190 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	OR	OFF	2001/07/25 08:55
		349/153 and (conduct\$ or dummy)and insulat\$	USPAT	OR	OFF	2001/07/25 08:53
		349/153 and (conduct\$ or dummy)	USPAT	OR	OFF	2004/11/24 14:56
		349/190 and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	OR	OFF	2004/11/29 13:02
L2	29	(conduct\$4 or dummy) near10 pitch near10 (gate scan\$4 data signal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/03 15:33
S1	136	349/190	USPAT	OR	OFF	2003/11/06 15:07
S2	321	349/155	USPAT	OR	OFF	2001/07/25 08:40
S3	444	349/149	USPAT	OR	OFF	2001/07/25 08:40
S4	176	349/151	USPAT	OR	OFF	2001/07/25 08:40
S5	309	345/206	USPAT	OR	OFF	2001/07/25 08:42
S6	298	349/153	USPAT	OR	OFF	2001/07/26 08:15
S7	1	"5995189".pn.	USPAT	OR	OFF	2002/02/25 10:05
S8	4	349/153 and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	OR	OFF	2002/05/13 10:06

S9	407	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	OR	OFF	2004/11/24 09:47
S10	125	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$ and seal\$4	USPAT	OR	OFF	2002/05/13 12:53
S11	33	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$ and seal\$4 and semiconductor.as.	USPAT	OR	OFF	2003/11/06 17:39
S12	165	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$ and seal\$4 and semiconductor.as.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/25 09:48
S13	96	349/153 and (conduct\$ or dummy)and insulat\$ and overlap\$	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/25 10:16
S14	6	349/153 and 349/141	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/25 10:39
S15	1	JP02214934.ap.	JPO	OR	OFF	2003/11/06 15:09
S16	1	JP04219642.ap.	JPO	OR	OFF	2003/11/06 16:10
S17	755	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and semiconductor.as.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:40
S18	672	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:41
S19	0	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as. and "349"/\$.ccls.	USOCR	OR	ON	2003/11/06 17:41
S20	139	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as. and "349"/\$.ccls.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:48
S21	140	(conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as. and "349"/\$.ccls.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:49
S22	89	(conduct\$ or dummy)and (gate or scan\$4)and (data or signal)and seal\$4 and insulat\$5 and semiconductor.as. and "349"/\$.ccls.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:51
S23	5	((conduct\$ or dummy)and (gate or scan\$4)and (data or signal)and seal\$4) near10 insulat\$5 and semiconductor.as. and "349"/\$.ccls.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:55

S24	79	((conduct\$ or dummy)and (gate or scan\$4)and (data or signal)and seal\$4) near10 insulat\$5 and "349"/\$. ccls.	US-PGPUB; USPAT; JPO	OR	ON	2003/11/06 17:56
S25	1	"20040179164".pn.	US-PGPUB	OR	OFF	2004/09/21 08:54
S26	10	349/153 and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	OR	OFF	2004/11/20 10:08
S27	11	349/153 and (conduct\$ or dummy)and (top adj gate) and crystal\$	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/20 10:08
S28	1716	(liquid adj crystal) and (conduct\$4 or dummy)and (top adj gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/20 10:48
S29	1716	(liquid adj crystal) and (conduct\$4 or dummy)and (top adj gate) and crystal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/20 10:49
S31	1	"5200847".pn.	USPAT	OR	OFF	2004/11/20 10:54
S32	23	"5148301".pn. "5179460".pn. "5200847".pn. "5323042".pn. "5396356".pn. "5517344".pn. "5537235".pn. "5572046".pn. "5598283".pn. "5619358".pn. "5621553".pn. "5684547".pn. "5684555".pn. "5691793".pn. "5706069".pn. "5745208".pn. "5798812".pn. "5929959".pn. "5995189".pn. "6011607".pn. "6037005".pn. "6055034".pn. "6072556".pn.	USPAT	OR	ON	2004/11/23 15:36
S33	73	(liquid adj crystal) and ((conduct\$4 or dummy) near10 seal\$4)and (top adj gate) and crystal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:45
S34	2873722	(conduct\$4 or dummy)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 09:57

S35	565691	(conduct\$4 or dummy) near10 material	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 09:57
S36	23834	(conduct\$4 or dummy) near10 material near10 (gate scan\$4 data signal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/03 15:31
S37	131	((conduct\$4 or dummy) near10 material near10 (gate scan\$4 data signal)) near10 seal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 11:44
S38	11	((conduct\$4 or dummy) near10 material near10 (gate scan\$4 data signal)) near10 seal\$4 and (seal\$4 near10 drive\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 10:00
S39	23834	((conduct\$4 or dummy) near10 material near10 (gate scan\$4 data signal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 11:45
S40	2949	((conduct\$4 or dummy) near10 material near10 (gate scan\$4 data signal)) and (liquid adj crystal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 11:46
S41	1228	((conduct\$4 or dummy) near10 material near10 (gate scan\$4 data signal)) and (liquid adj crystal)and seal\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 11:46
S42	201	((conduct\$4 or dummy) near10 material near10 (gate scan\$4 data signal)) and (liquid adj crystal)and seal\$4 and (top adj gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 11:48

S43	96	((conduct\$4 or dummy) near10 material near10 (gate scan\$4 data signal)) and (liquid adj crystal)and seal\$4 and (top adj gate)and rectangular	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 14:50
S44	74	((conduct\$4 or dummy) near10 material near10 (gate scan\$4 data signal)) near10 rectangular	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 14:53
S45	13	((conduct\$4 or dummy) near10 material near10 (gate scan\$4 data signal)) near10 rectangular and (liquid adj crystal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 14:54
S46	617	349/153 and (conduct\$ or dummy)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 14:58
S48	83	349/190 and ((conduct\$ or dummy) near10 seal\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 16:23
S49	4	((rectangular adj wave) or zogzag) near10 ((conduct\$4 or dummy) near10 seal\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 16:26
S50	266	349/153 and ((conduct\$ or dummy) near10 seal\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/24 16:32
S51	2025	(top adj gate) and (liquid adj crystal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 13:04

S52	1732	(top adj gate) and (liquid adj crystal) and (conduct\$4 or dummy)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 13:09
S53	13	(top adj gate) and (liquid adj crystal) and ((conduct\$4 or dummy) near10 (rectangular or zigzag))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 13:05
S54	358	(top adj gate) and "349"/\$.ccls. and (conduct\$4 or dummy)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 14:14
S55	5	(top adj gate) and "349"/\$.ccls. and ((conduct\$4 or dummy) near10 (zigzag or rectangular))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 14:16
S56	226	"349"/\$.ccls. and ((conduct\$4 or dummy) near10 (zigzag or rectangular))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 14:16
S57	2794	(TFT or (thin adj film adj transistor)) near10 crystalline	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 17:59
S58	209	((TFT or (thin adj film adj transistor)) near10 crystalline) and "349"/\$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 17:59